**ON Semiconductor** 

Is Now

# Onsemi

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# Quad 2-Input Exclusive-OR Gate

# High–Performance Silicon–Gate CMOS

# Features

- Outputs Source/Sink 24 mA
- These are Pb–Free Devices

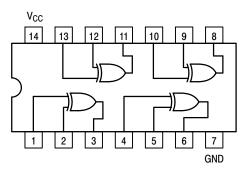
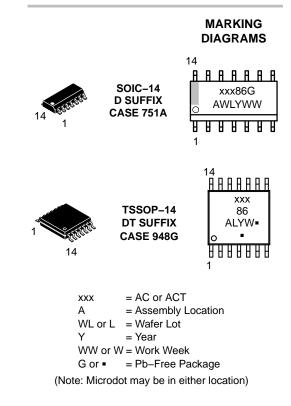


Figure 1. Pinout: 14–Lead Packages Conductors (Top View)



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# ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

#### MAXIMUM RATINGS

| Symbol                | Parameter   |   | Value                             | Unit |
|-----------------------|---|---|-----------------------------------|------|
| V <sub>CC</sub>       | DC Supply Voltage                                   |   | -0.5 to +7.0                      | V    |
| VI                    | DC Input Voltage                                    |   | $-0.5 \le V_{I} \le V_{CC} + 0.5$ | V    |
| V <sub>O</sub>        | DC Output Voltage                                   | (Note 1)  | $-0.5 \leq V_O \leq V_{CC} + 0.5$ | V    |
| I <sub>IK</sub>       | DC Input Diode Current                              |   | ±20                               | mA   |
| I <sub>OK</sub>       | DC Output Diode Current                             |   | ±50                               | mA   |
| I <sub>O</sub>        | DC Output Sink/Source Current                       |   | ±50                               | mA   |
| I <sub>CC</sub>       | DC Supply Current per Output Pin                    |   | ±50                               | mA   |
| I <sub>GND</sub>      | DC Ground Current per Output Pin                    |   | ±50                               | mA   |
| T <sub>STG</sub>      | Storage Temperature Range                           |   | -65 to +150                       | °C   |
| TL                    | Lead temperature, 1 mm from Case for 10 Sec         | conds   | 260                               | °C   |
| TJ                    | Junction temperature under Bias                     |   | + 150                             | °C   |
| $\theta_{JA}$         | Thermal Resistance (Note 2)                         | SOIC<br>TSSOP   | 125<br>170                        | °C/W |
| P <sub>D</sub>        | Power Dissipation in Still Air at 85°C              | SOIC<br>TSSOP   | 125<br>170                        | mW   |
| MSL                   | Moisture Sensitivity                                |   | Level 1                           |      |
| F <sub>R</sub>        | Flammability Rating O                               | xygen Index: 30% – 35%  | UL 94 V-0 @ 0.125 in              |      |
| V <sub>ESD</sub>      | , i i i i i i i i i i i i i i i i i i i             | nan Body Model (Note 3)<br>Machine Model (Note 4)<br>ed Device Model (Note 5) | > 2000<br>> 200<br>> 1000         | V    |
| I <sub>Latch-Up</sub> | Latch–Up Performance Above V <sub>CC</sub> and Belo | ow GND at 85°C (Note 6)   | ±100                              | mA   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I<sub>O</sub> absolute maximum rating must be observed.

The package thermal impedance is calculated in accordance with JESD51–7.
 Tested to EIA/JESD22–A114–A.

4. Tested to EIA/JESD22-A115-A.

5. Tested to JESD22-C101-A.

6. Tested to EIA/JESD78.

# **RECOMMENDED OPERATING CONDITIONS**

| Symbol                             | Parameter  |                         |     | Тур | Max             | Unit         |
|------------------------------------|--|-------------------------|-----|-----|-----------------|--------------|
|                                    |  | 'AC                     |     | 5.0 | 6.0             | Ň            |
| V <sub>CC</sub>                    | Supply Voltage                                       | ′ACT                    | 4.5 | 5.0 | 5.5             | V            |
| V <sub>in</sub> , V <sub>out</sub> | DC Input Voltage, Output Voltage (Ref. to GND)       |                         | 0   |     | V <sub>CC</sub> | V            |
|                                    |  | V <sub>CC</sub> @ 3.0 V | -   | 150 | -               |              |
| t <sub>r</sub> , t <sub>f</sub>    | n, t <sub>f</sub> / AC Devices except Schmitt Inputs | V <sub>CC</sub> @ 4.5 V | -   | 40  | -               | ns/V         |
|                                    |  | V <sub>CC</sub> @ 5.5 V | -   | 25  | -               |              |
|                                    | Input Rise and Fall Time (Note 2)                    | V <sub>CC</sub> @ 4.5 V | -   | 10  | -               | <b>no</b> // |
| t <sub>r</sub> , t <sub>f</sub>    | ACT Devices except Schmitt Inputs                    | V <sub>CC</sub> @ 5.5 V | -   | 8.0 | -               | ns/V         |
| TJ                                 | Junction Temperature (PDIP)                          |                         | _   | _   | 140             | °C           |
| T <sub>A</sub>                     | Operating Ambient Temperature Range                  |                         | -40 | 25  | 85              | °C           |
| I <sub>OH</sub>                    | Output Current – High                                |                         | -   | -   | -24             | mA           |
| I <sub>OL</sub>                    | Output Current – Low                                 |                         | -   | -   | 24              | mA           |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 1.  $V_{in}$  from 30% to 70%  $V_{CC}$ ; see individual Data Sheets for devices that differ from the typical input rise and fall times. 2.  $V_{in}$  from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

#### **DC CHARACTERISTICS**

|                  |                                      |                   | 74  | AC                   | 74AC                 |      |   |
|------------------|--------------------------------------|-------------------|---|----------------------|----------------------|------|---|
|                  |                                      | v <sub>cc</sub>   | $T_{A} = -40^{\circ}C \text{ to}$ $T_{A} = +25^{\circ}C +85^{\circ}C$ |                      |                      |      |   |
| Symbol           | Parameter                            | (V)               | Тур   | Guar                 | anteed Limits        | Unit | Conditions  |
| V <sub>IH</sub>  | Minimum High Level<br>Input Voltage  | 3.0<br>4.5<br>5.5 | 1.5<br>2.25<br>2.75   | 2.1<br>3.15<br>3.85  | 2.1<br>3.15<br>3.85  | V    | $V_{OUT} = 0.1 V$<br>or $V_{CC} - 0.1 V$  |
| V <sub>IL</sub>  | Maximum Low Level<br>Input Voltage   | 3.0<br>4.5<br>5.5 | 1.5<br>2.25<br>2.75   | 0.9<br>1.35<br>1.65  | 0.9<br>1.35<br>1.65  | V    | $V_{OUT} = 0.1 V$<br>or $V_{CC} - 0.1 V$  |
| V <sub>OH</sub>  | Minimum High Level<br>Output Voltage | 3.0<br>4.5<br>5.5 | 2.99<br>4.49<br>5.49  | 2.9<br>4.4<br>5.4    | 2.9<br>4.4<br>5.4    | V    | I <sub>OUT</sub> = –50 μA   |
|                  |                                      | 3.0<br>4.5<br>5.5 |   | 2.56<br>3.86<br>4.86 | 2.46<br>3.76<br>4.76 | V    | $\label{eq:VIN} \begin{array}{c} {}^{*}V_{IN} = V_{IL} \text{ or } V_{IH} \\ -12 \text{ mA} \\ I_{OH} -24 \text{ mA} \\ -24 \text{ mA} \end{array}$ |
| V <sub>OL</sub>  | Maximum Low Level<br>Output Voltage  | 3.0<br>4.5<br>5.5 | 0.002<br>0.001<br>0.001   | 0.1<br>0.1<br>0.1    | 0.1<br>0.1<br>0.1    | V    | Ι <sub>ΟUT</sub> = 50 μΑ  |
|                  |                                      | 3.0<br>4.5<br>5.5 |   | 0.36<br>0.36<br>0.36 | 0.44<br>0.44<br>0.44 | V    | $\label{eq:VIN} \begin{array}{c} {}^{*}V_{IN} = V_{IL} \text{ or } V_{IH} \\ 12 \text{ mA} \\ I_{OL} \\ 24 \text{ mA} \\ 24 \text{ mA} \end{array}$ |
| I <sub>IN</sub>  | Maximum Input<br>Leakage Current     | 5.5               | -   | ±0.1                 | ±1.0                 | μΑ   | $V_{I} = V_{CC}, GND$   |
| I <sub>OLD</sub> | †Minimum Dynamic                     | 5.5               | -   | -                    | 75                   | mA   | V <sub>OLD</sub> = 1.65 V Max   |
| I <sub>OHD</sub> | Output Current                       | 5.5               | -   | -                    | -75                  | mA   | V <sub>OHD</sub> = 3.85 V Min   |
| I <sub>CC</sub>  | Maximum Quiescent<br>Supply Current  | 5.5               | _   | 4.0                  | 40                   | μΑ   | $V_{IN} = V_{CC} \text{ or } GND$   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. \*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time. NOTE:  $I_{IN}$  and  $I_{CC}$  @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V<sub>CC</sub>.

## AC CHARACTERISTICS

|                  |  |                   |            | 74AC                 |             | 74/   | AC          |      |      |
|------------------|--|-------------------|------------|----------------------|-------------|---|-------------|------|------|
|                  |  | V <sub>CC</sub> * | T,<br>C    | a = +25°<br>∟ = 50 p | C<br>F      | T <sub>A</sub> = -<br>to +8<br>C <sub>L</sub> = 5 | 35°C        |      | Fig. |
| Symbol           | Parameter                              | (V)               | Min        | Тур                  | Max         | Min   | Max         | Unit | No.  |
| t <sub>PLH</sub> | Propagation Delay<br>Inputs to Outputs | 3.3<br>5.0        | 2.0<br>1.5 | 6.0<br>4.5           | 11.5<br>8.5 | 1.5<br>1.0  | 12.5<br>9.0 | ns   | 3–5  |
| t <sub>PHL</sub> | Propagation Delay<br>Inputs to Outputs | 3.3<br>5.0        | 2.0<br>1.5 | 6.5<br>4.5           | 11.5<br>8.5 | 1.5<br>1.0  | 12.5<br>9.5 | ns   | 3–5  |

\*Voltage Range 3.3 V is 3.3 V ±0.3 V Voltage Range 5.0 V is 5.0 V ±0.5 V.

#### **DC CHARACTERISTICS**

|                  |  |                 | 74 <i>A</i>            | СТ           | 74ACT                                 |      |  |
|------------------|--|-----------------|------------------------|--------------|---------------------------------------|------|--|
|                  |  | V <sub>CC</sub> | T <sub>A</sub> = +25°C |              | T <sub>A</sub> =<br>–40°C to<br>+85°C |      |  |
| Symbol           | Parameter                              | (Ŭ)             | Тур                    | Guar         | anteed Limits                         | Unit | Conditions   |
| V <sub>IH</sub>  | Minimum High Level<br>Input Voltage    | 4.5<br>5.5      | 1.5<br>1.5             | 2.0<br>2.0   | 2.0<br>2.0                            | V    | $V_{OUT} = 0.1 V$<br>or $V_{CC} - 0.1 V$   |
| V <sub>IL</sub>  | Maximum Low Level<br>Input Voltage     | 4.5<br>5.5      | 1.5<br>1.5             | 0.8<br>0.8   | 0.8<br>0.8                            | V    | $V_{OUT} = 0.1 V$<br>or $V_{CC} - 0.1 V$   |
| V <sub>OH</sub>  | Minimum High Level<br>Output Voltage   | 4.5<br>5.5      | 4.49<br>5.49           | 4.4<br>5.4   | 4.4<br>5.4                            | V    | I <sub>OUT</sub> = -50 μA  |
|                  |  | 4.5<br>5.5      |                        | 3.86<br>4.86 | 3.76<br>4.76                          | V    | $V_{IN} = V_{IL} \text{ or } V_{IH}$<br>-24 mA<br>$I_{OH}$ -24 mA                              |
| V <sub>OL</sub>  | Maximum Low Level<br>Output Voltage    | 4.5<br>5.5      | 0.001<br>0.001         | 0.1<br>0.1   | 0.1<br>0.1                            | V    | I <sub>OUT</sub> = 50 μA   |
|                  |  | 4.5<br>5.5      |                        | 0.36<br>0.36 | 0.44<br>0.44                          | V    | $V_{IN} = V_{IL} \text{ or } V_{IH}$<br>$V_{IOL} = 24 \text{ mA}$<br>$V_{IOL} = 24 \text{ mA}$ |
| I <sub>IN</sub>  | Maximum Input<br>Leakage Current       | 5.5             |                        | ±0.1         | ±1.0                                  | μΑ   | $V_{I} = V_{CC}, GND$  |
| $\Delta I_{CCT}$ | Additional Max. I <sub>CC</sub> /Input | 5.5             | 0.6                    | -            | 1.5                                   | mA   | $V_{I} = V_{CC} - 2.1 V$   |
| I <sub>OLD</sub> | †Minimum Dynamic                       | 5.5             | -                      | -            | 75                                    | mA   | $V_{OLD}$ = 1.65 V Max   |
| I <sub>OHD</sub> | Output Current                         | 5.5             | -                      | -            | -75                                   | mA   | V <sub>OHD</sub> = 3.85 V Min  |
| Icc              | Maximum Quiescent<br>Supply Current    | 5.5             | -                      | 4.0          | 40                                    | μΑ   | $V_{IN} = V_{CC}$ or GND   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. \*All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

## **AC CHARACTERISTICS**

|                  |                   |                   |     | 74ACT                |     | 74A  | СТ   |      |      |
|------------------|-------------------|-------------------|-----|----------------------|-----|--|------|------|------|
|                  |                   | V <sub>CC</sub> * |     | ₄ = +25°<br>L = 50 p |     | T <sub>A</sub> = -<br>to +8<br>C <sub>L</sub> = \$ | 35°C |      | Fig. |
| Symbol           | Parameter         | (V)               | Min | Тур                  | Max | Min  | Max  | Unit | No.  |
| t <sub>PLH</sub> | Propagation Delay | 5.0               | 1.5 | 8.5                  | 9.5 | 1.0  | 10.0 | ns   | 3–5  |
| t <sub>PHL</sub> | Propagation Delay | 5.0               | 1.5 | 7.0                  | 9.5 | 1.0  | 10.5 | ns   | 3–5  |

\*Voltage Range 5.0 V is 5.0 V  $\pm$ 0.5 V.

# CAPACITANCE

| Symbol          | Parameter                     | Value<br>Typ | Unit | Test Conditions  |
|-----------------|-------------------------------|--------------|------|------------------|
| C <sub>IN</sub> | Input Capacitance             | 4.5          | pF   | $V_{CC} = 5.0 V$ |
| C <sub>PD</sub> | Power Dissipation Capacitance | 35           | pF   | $V_{CC} = 5.0 V$ |

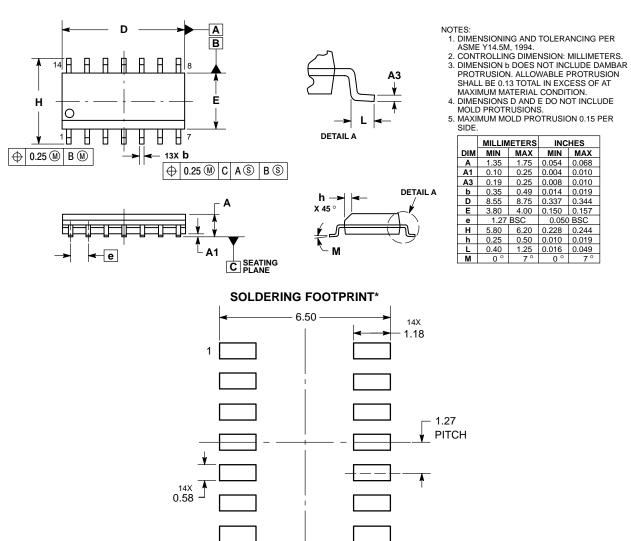
## **ORDERING INFORMATION**

| Device         | Package               | Shipping <sup>†</sup> |
|----------------|-----------------------|-----------------------|
| MC74AC86DG     | SOIC-14               | 55 Units / Rail       |
| MC74AC86DR2G   | (Pb-Free)             | 2500 / Tape & Reel    |
| MC74AC86DTR2G  | TSSOP-14<br>(Pb-Free) | 2500 / Tape & Reel    |
| MC74ACT86DG    | SOIC-14               | 55 Units / Rail       |
| MC74ACT86DR2G  | (Pb-Free)             | 2500 / Tape & Reel    |
| MC74ACT86DTR2G | TSSOP-14<br>(Pb-Free) | 2500 / Tape & Reel    |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# PACKAGE DIMENSIONS

SOIC-14 NB CASE 751A-03 ISSUE K

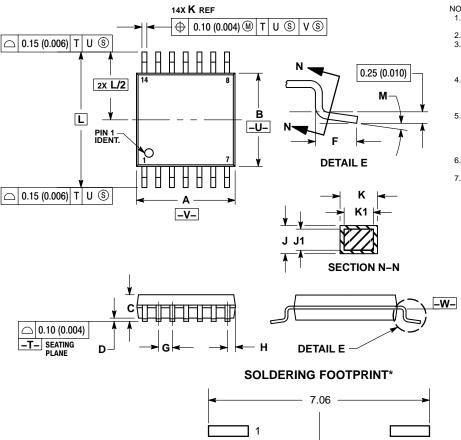


DIMENSIONS: MILLIMETERS

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## PACKAGE DIMENSIONS

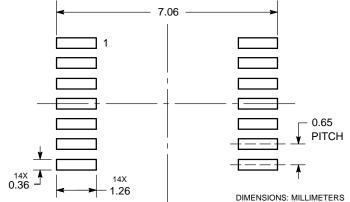
TSSOP-14 CASE 948G **ISSUE B** 



NOTES:

- NOTES:
  DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETER.
  DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
  DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION. SHALL NOT EXCEED 0.25
- OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
- (0.010) PER SIDE. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION. TERMINAL NUMBER ARE SHOWNLEOP
- TERMINAL NUMBERS ARE SHOWN FOR
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
  DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE W–.

|     | MILLIMETERS |      | INCHES    |       |  |
|-----|-------------|------|-----------|-------|--|
| DIM | MIN         | MAX  | MIN       | MAX   |  |
| Α   | 4.90        | 5.10 | 0.193     | 0.200 |  |
| В   | 4.30        | 4.50 | 0.169     | 0.177 |  |
| С   |             | 1.20 |           | 0.047 |  |
| D   | 0.05        | 0.15 | 0.002     | 0.006 |  |
| F   | 0.50        | 0.75 | 0.020     | 0.030 |  |
| G   | 0.65        | BSC  | 0.026 BSC |       |  |
| Н   | 0.50        | 0.60 | 0.020     | 0.024 |  |
| J   | 0.09        | 0.20 | 0.004     | 0.008 |  |
| J1  | 0.09        | 0.16 | 0.004     | 0.006 |  |
| κ   | 0.19        | 0.30 | 0.007     | 0.012 |  |
| K1  | 0.19        | 0.25 | 0.007     | 0.010 |  |
| L   | 6.40        |      | 0.252 BSC |       |  |
| Μ   | 0 °         | 8 °  | 0 °       | 8 °   |  |



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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